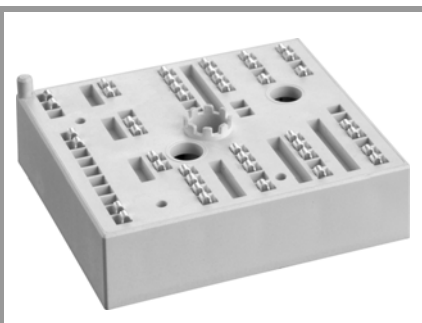


SKiIP 25AC12T4V25



MiniSKiIP® 2

Sixpack

SKiIP 25AC12T4V25

Features*

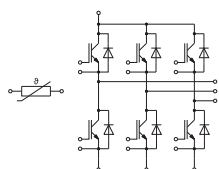
- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

Typical Applications

- Inverter up to 26 kVA
- Typical motor power 15 kW

Remarks

- V_{CEsat} , V_F = chip level value
- Case temp. limited to $T_C = 125^\circ\text{C}$ max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_j \leq 150$ (recomm. $T_{op} = -40 \dots +150^\circ\text{C}$)
- Dynamic test results for $V_{CC} = 600\text{V}$, $R_{Gon/off} = 12\Omega$, $I_C = 50\text{A}$, $V_{GE} = \pm 15\text{V}$: $E_{on} = 5.6\text{mJ}$, $E_{off} = 6.1\text{mJ}$, $E_{rr} = 3.3\text{mJ}$, $di/dt_{on} = 1440\text{A}/\mu\text{s}$, $t_{don} = 58\text{ns}$, $t_r = 43\text{ns}$, $di/dt_{off} = 600\text{A}/\mu\text{s}$, $t_{doff} = 370\text{ns}$, $t_f = 65\text{ns}$



AC

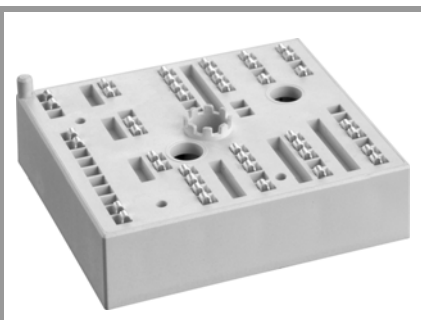
Absolute Maximum Ratings

Symbol	Conditions	Values	Unit
Inverter - IGBT			
V_{CES}	$T_j = 25^\circ\text{C}$	1200	V
I_C	$\lambda_{paste}=0.8\text{ W}/(\text{mK})$	$T_s = 25^\circ\text{C}$	68
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	55
I_C	$\lambda_{paste}=2.5\text{ W}/(\text{mK})$	$T_s = 25^\circ\text{C}$	t.b.d.
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	t.b.d.
I_{Cnom}		50	A
I_{CRM}		150	A
V_{GES}		-20 ... 20	V
t_{psc}	$V_{CC} = 800\text{ V}$ $V_{GE} \leq 15\text{ V}$ $V_{CES} \leq 1200\text{ V}$	$T_j = 150^\circ\text{C}$	10
T_j		-40 ... 175	$^\circ\text{C}$
Inverse - Diode			
V_{RRM}	$T_j = 25^\circ\text{C}$	1200	V
I_F	$\lambda_{paste}=0.8\text{ W}/(\text{mK})$	$T_s = 25^\circ\text{C}$	60
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	48
I_F	$\lambda_{paste}=2.5\text{ W}/(\text{mK})$	$T_s = 25^\circ\text{C}$	t.b.d.
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	t.b.d.
I_{FRM}		100	A
I_{FSM}	$t_p = 10\text{ ms}$, $\sin 180^\circ$, $T_j = 150^\circ\text{C}$	270	A
T_j		-40 ... 175	$^\circ\text{C}$
Module			
$I_t(\text{RMS})$	$T_{terminal} = 80^\circ\text{C}$, 20 A per spring	60	A
T_{stg}	module without TIM	-40 ... 125	$^\circ\text{C}$
V_{isol}	AC sinus 50 Hz, $t = 1\text{ min}$	2500	V

Characteristics

Symbol	Conditions	min.	typ.	max.	Unit
Inverter - IGBT					
$V_{CE(sat)}$	$I_C = 50\text{ A}$ $V_{GE} = 15\text{ V}$ chiplevel	$T_j = 25^\circ\text{C}$	1.85	2.10	V
		$T_j = 150^\circ\text{C}$	2.20	2.40	V
V_{CE0}	chiplevel	$T_j = 25^\circ\text{C}$	0.80	0.90	V
		$T_j = 150^\circ\text{C}$	0.70	0.80	V
r_{CE}	$V_{GE} = 15\text{ V}$ chiplevel	$T_j = 25^\circ\text{C}$	21	24	m Ω
		$T_j = 150^\circ\text{C}$	30	32	m Ω
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 1.7\text{ mA}$	5	5.8	6.5	V
I_{CES}	$V_{GE} = 0\text{ V}$, $V_{CE} = 1200\text{ V}$, $T_j = 25^\circ\text{C}$			1	mA
C_{ies}	$V_{CE} = 25\text{ V}$ $V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	2.77		nF
C_{oes}		$f = 1\text{ MHz}$	0.21		nF
C_{res}		$f = 1\text{ MHz}$	0.16		nF
Q_G	$V_{GE} = -8\text{ V} \dots +15\text{ V}$		283		nC
R_{Gint}	$T_j = 25^\circ\text{C}$		4.0		Ω
$t_{d(on)}$	$V_{CC} = 800\text{ V}$	$T_j = 150^\circ\text{C}$	45		ns
t_r	$I_C = 22\text{ A}$ $R_{Gon} = 12\Omega$	$T_j = 150^\circ\text{C}$	19		ns
		$T_j = 150^\circ\text{C}$	3.4		mJ
E_{on}	$R_{Goff} = 1\Omega$	$T_j = 150^\circ\text{C}$	3.4		mJ
$t_{d(off)}$	$di/dt_{on} = 1640\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	480		ns
t_f	$di/dt_{off} = 320\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	44		ns
E_{off}	$V_{GE} = +15/0\text{ V}$	$T_j = 150^\circ\text{C}$	3.1		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=0.8\text{ W}/(\text{mK})$		0.71		K/W
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=2.5\text{ W}/(\text{mK})$		t.b.d.		K/W

SKiiP 25AC12T4V25



MiniSKiiP® 2

Sixpack

SKiiP 25AC12T4V25

Features*

- Trench 4 IGBTs
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

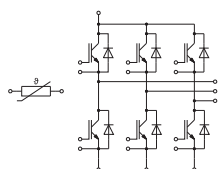
Typical Applications

- Inverter up to 26 kVA
- Typical motor power 15 kW

Remarks

- V_{CEsat} , V_F = chip level value
- Case temp. limited to $T_C = 125^\circ\text{C}$ max. (for baseplateless modules $T_C = T_S$)
- product rel. results valid for $T_j \leq 150$ (recomm. $T_{op} = -40 \dots +150^\circ\text{C}$)
- Dynamic test results for $V_{CC} = 600\text{V}$, $R_{Gon/off} = 12\Omega$, $I_c = 50\text{A}$, $V_{GE} = \pm 15\text{V}$: $E_{on} = 5.6\text{mJ}$, $E_{off} = 6.1\text{mJ}$, $E_{rr} = 3.3\text{mJ}$, $di/dt_{on} = 1440\text{A}/\mu\text{s}$, $t_{don} = 58\text{ns}$, $t_r = 43\text{ns}$, $di/dt_{off} = 600\text{A}/\mu\text{s}$, $t_{doff} = 370\text{ns}$, $t_f = 65\text{ns}$

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverse - Diode						
$V_F = V_{EC}$	$I_F = 50\text{ A}$ $V_{GE} = 0\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		2.22	2.54	V
		$T_j = 150^\circ\text{C}$		2.18	2.50	V
V_{F0}	chipelevel	$T_j = 25^\circ\text{C}$		1.30	1.50	V
		$T_j = 150^\circ\text{C}$		0.90	1.10	V
r_F	chipelevel	$T_j = 25^\circ\text{C}$		18	21	m Ω
		$T_j = 150^\circ\text{C}$		26	28	m Ω
I_{RRM}	$I_F = 22\text{ A}$	$T_j = 150^\circ\text{C}$		0		A
Q_{rr}	$di/dt_{off} = 1680\text{ A}/\mu\text{s}$ $V_{GE} = +15/0\text{ V}$	$T_j = 150^\circ\text{C}$		5.5		μC
E_{rr}	$V_{CC} = 800\text{ V}$	$T_j = 150^\circ\text{C}$		2.9		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 0.8\text{ W}/(\text{mK})$			0.95		K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 2.5\text{ W}/(\text{mK})$			t.b.d.		K/W
Module						
L_{CE}				-		nH
M_s	to heat sink		2		2.5	Nm
w				55		g
Temperature Sensor						
R_{100}	$T_r = 100^\circ\text{C}$ ($R_{25} = 1000\Omega$)			$1670 \pm 3\%$		Ω
$R_{(T)}$	$R_{(T)} = 1000\Omega [1 + A(T - 25^\circ\text{C}) + B(T - 25^\circ\text{C})^2]$, $A = 7.635 \cdot 10^{-3} \text{ }^\circ\text{C}^{-1}$, $B = 1.731 \cdot 10^{-5} \text{ }^\circ\text{C}^{-2}$					



AC

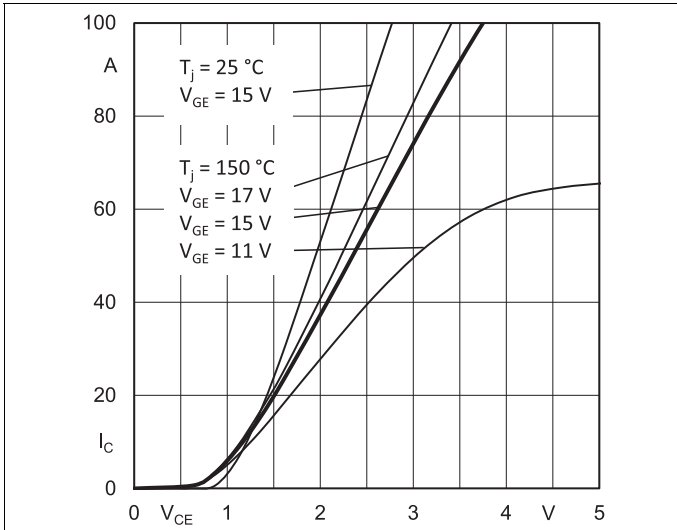


Fig. 1: Typ. output characteristic

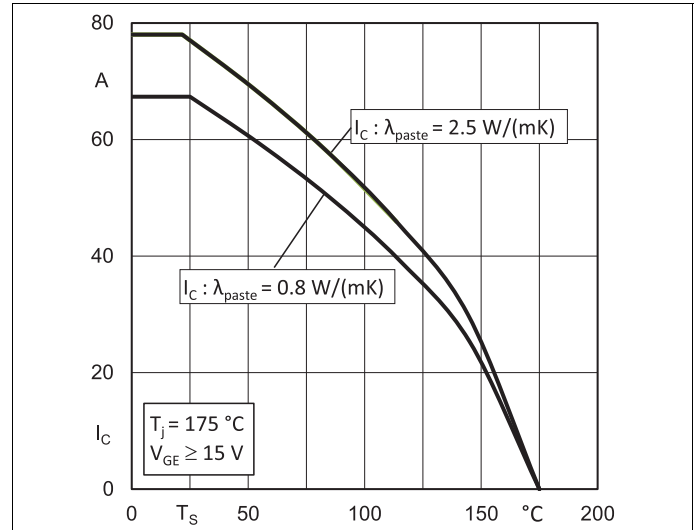


Fig. 2: Rated current vs. temperature $I_C = f(T_s)$

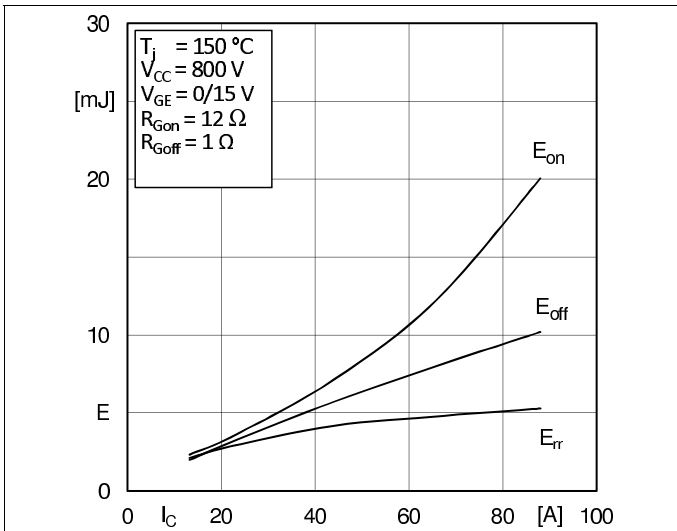


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

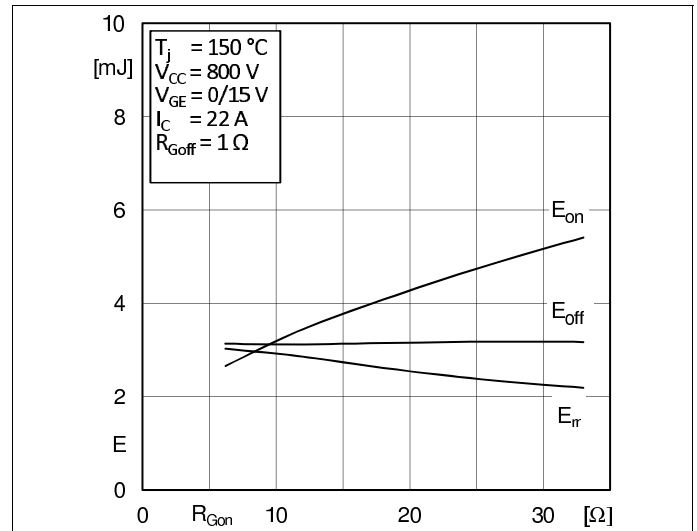


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

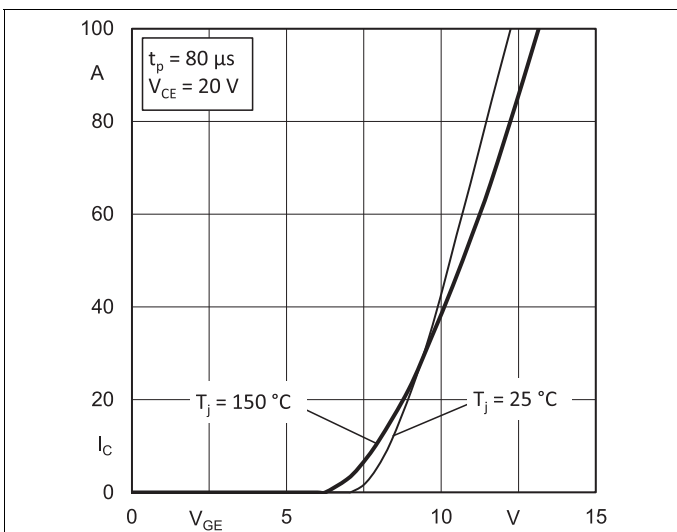


Fig. 5: Typ. transfer characteristic

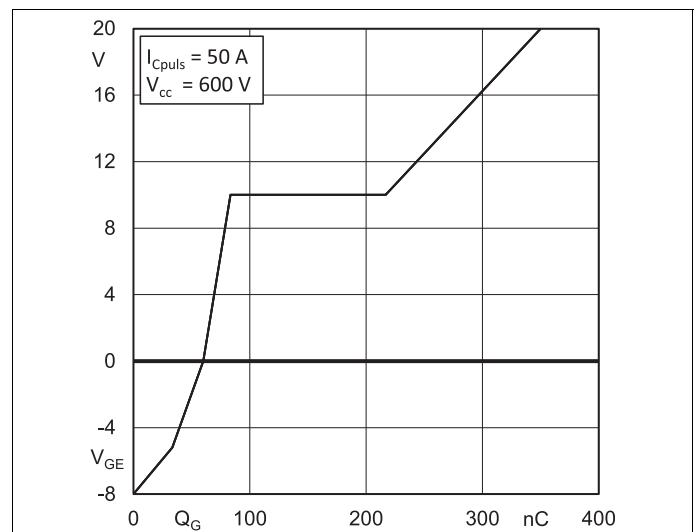


Fig. 6: Typ. gate charge characteristic

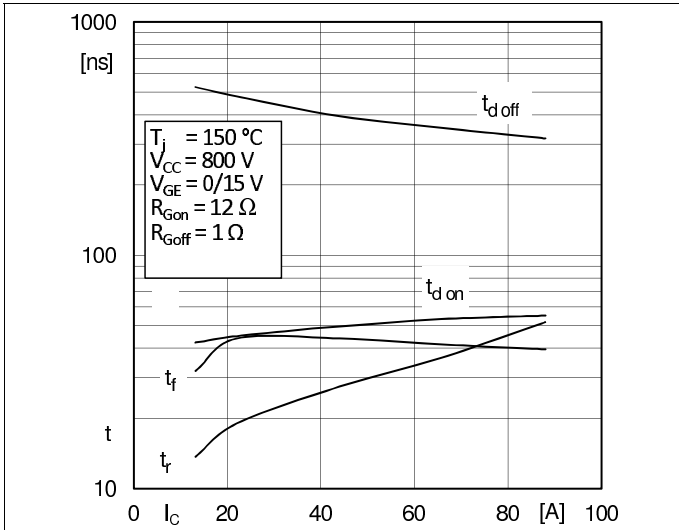


Fig. 7: Typ. switching times vs. I_C

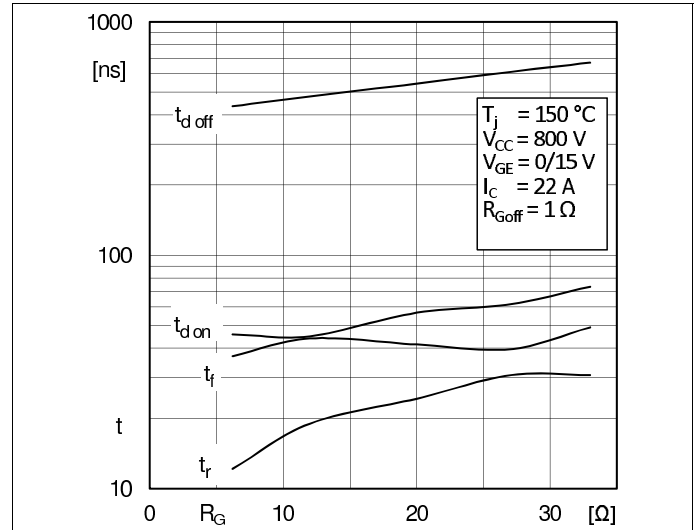


Fig. 8: Typ. switching times vs. gate resistor R_G

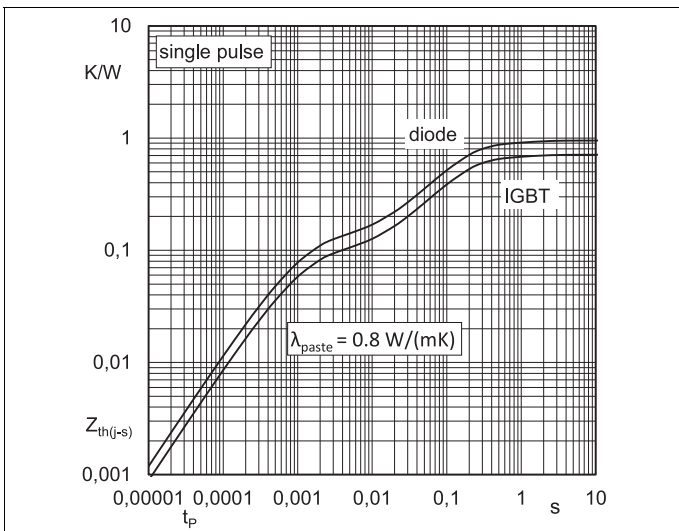


Fig. 9: Typ. transient thermal impedance

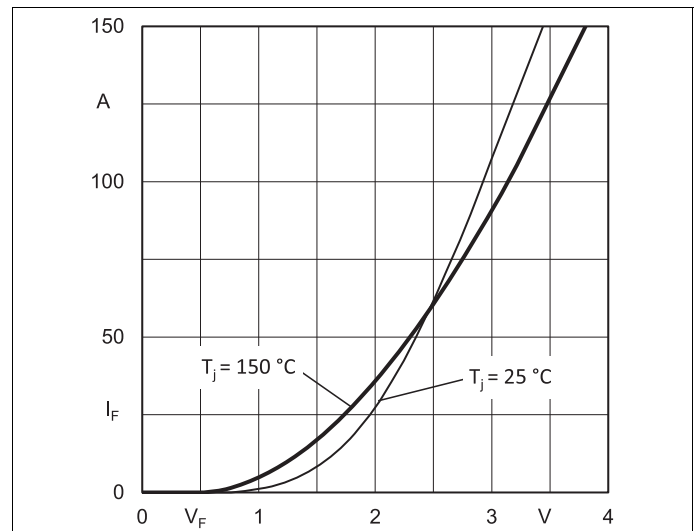


Fig. 10: Typ. CAL diode forward characteristic

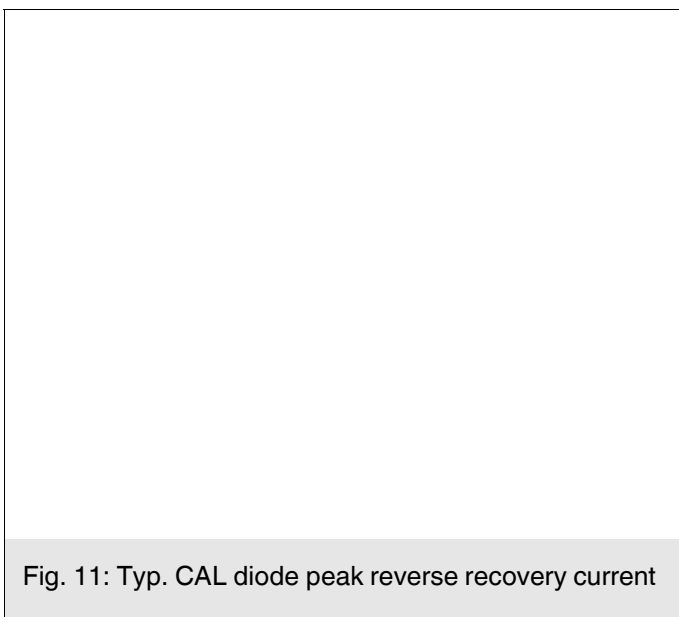


Fig. 11: Typ. CAL diode peak reverse recovery current

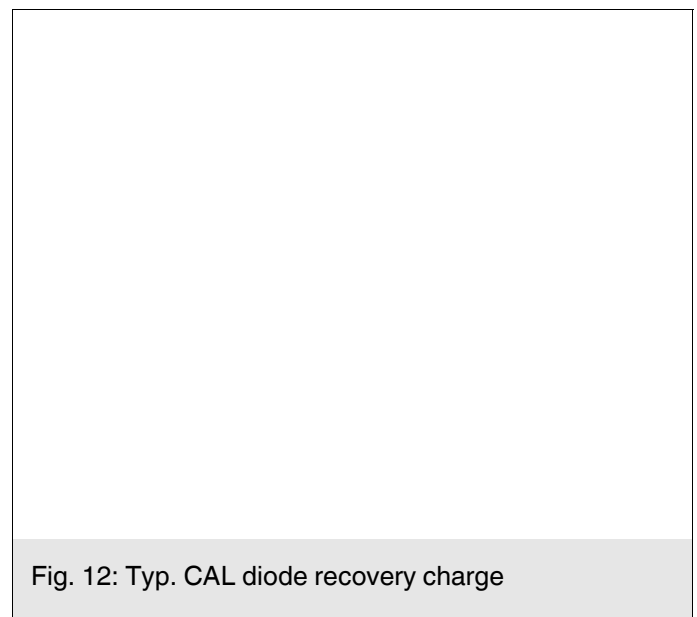
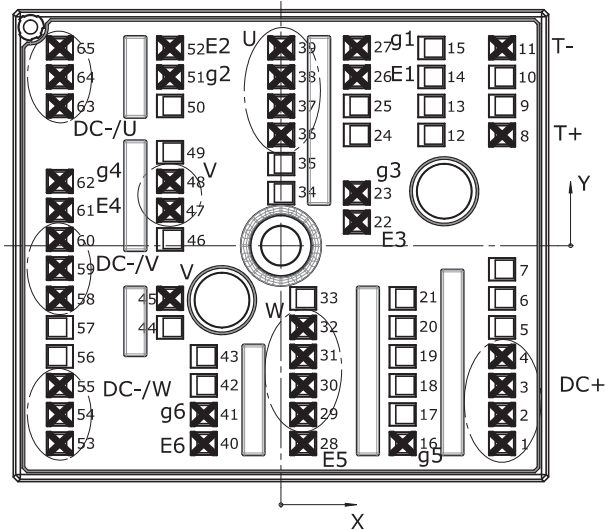


Fig. 12: Typ. CAL diode recovery charge

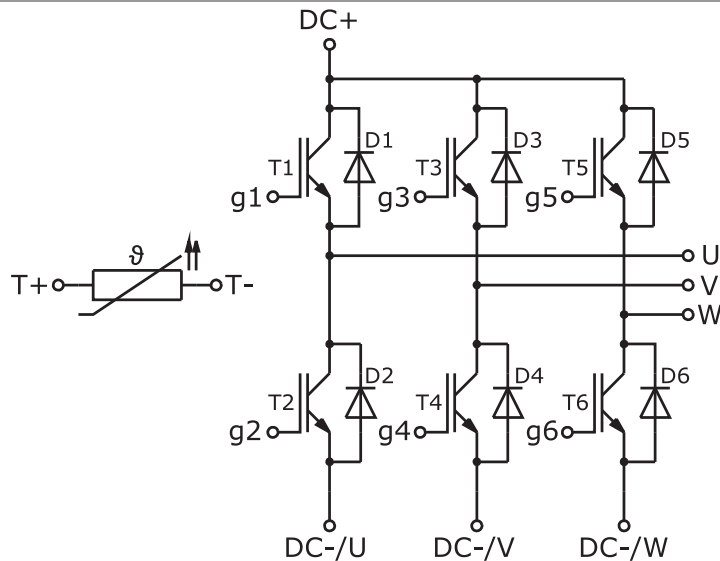
SKiP 25AC12T4V25

Pin out											
Pin	X	Y	Function	Pin	X	Y	Function	Pin	X	Y	Function
1	24,38	-21,80	DC+	23	8,38	5,80	g3	45	-12,23	-5,80	V
2	24,38	-18,60	DC+	24	8,38	12,20		46	-12,23	0,70	
3	24,38	-15,40	DC+	25	8,38	15,40		47	-12,23	3,90	V
4	24,38	-12,20	DC+	26	8,38	18,60	E1	48	-12,23	7,10	V
5	24,38	-9,00		27	8,38	21,80	g1	49	-12,23	10,30	
6	24,38	-5,80		28	2,46	-21,80	E5	50	-12,23	15,40	
7	24,38	-2,60		29	2,46	-18,60	W	51	-12,23	18,60	g2
8	24,38	12,20	T+	30	2,46	-15,40	W	52	-12,23	21,80	E2
9	24,38	15,40		31	2,46	-12,20	W	53	-24,38	-21,80	DC-/W
10	24,38	18,60		32	2,46	-9,00	W	54	-24,38	-18,60	DC-/W
11	24,38	21,80	T-	33	2,46	-5,80		55	-24,38	-15,40	DC-/W
12	16,58	12,20		34	0,03	5,80		56	-24,38	-12,20	
13	16,58	15,40		35	0,03	9,00		57	-24,38	-9,00	
14	16,58	18,60		36	0,03	12,20	U	58	-24,38	-5,80	DC-/V
15	16,58	21,80		37	0,03	15,40	U	59	-24,38	-2,50	DC-/V
16	13,42	-21,80	g5	38	0,03	18,60	U	60	-24,38	0,70	DC-/V
17	13,42	-18,60		39	0,03	21,80	U	61	-24,38	3,90	E4
18	13,42	-15,40		40	-8,51	-21,80	E6	62	-24,38	7,10	g4
19	13,42	-12,20		41	-8,51	-18,60	g6	63	-24,38	15,40	DC-/U
20	13,42	-9,00		42	-8,51	-15,40		64	-24,38	18,60	DC-/U
21	13,42	-5,80		43	-8,51	-12,20		65	-24,38	21,80	DC-/U
22	8,38	2,60	E3	44	-12,23	-9,00					

all values in mm



Pinout and Dimensions



Pinout

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

***IMPORTANT INFORMATION AND WARNINGS**

The specifications of SEMIKRON products may not be considered as guarantee or assurance of product characteristics ("Beschaffenheitsgarantie"). The specifications of SEMIKRON products describe only the usual characteristics of products to be expected in typical applications, which may still vary depending on the specific application. Therefore, products must be tested for the respective application in advance. Application adjustments may be necessary. The user of SEMIKRON products is responsible for the safety of their applications embedding SEMIKRON products and must take adequate safety measures to prevent the applications from causing a physical injury, fire or other problem if any of SEMIKRON products become faulty. The user is responsible to make sure that the application design is compliant with all applicable laws, regulations, norms and standards. Except as otherwise explicitly approved by SEMIKRON in a written document signed by authorized representatives of SEMIKRON, SEMIKRON products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury. No representation or warranty is given and no liability is assumed with respect to the accuracy, completeness and/or use of any information herein, including without limitation, warranties of non-infringement of intellectual property rights of any third party. SEMIKRON does not assume any liability arising out of the applications or use of any product; neither does it convey any license under its patent rights, copyrights, trade secrets or other intellectual property rights, nor the rights of others. SEMIKRON makes no representation or warranty of non-infringement or alleged non-infringement of intellectual property rights of any third party which may arise from applications. Due to technical requirements our products may contain dangerous substances. For information on the types in question please contact the nearest SEMIKRON sales office. This document supersedes and replaces all information previously supplied and may be superseded by updates. SEMIKRON reserves the right to make changes.